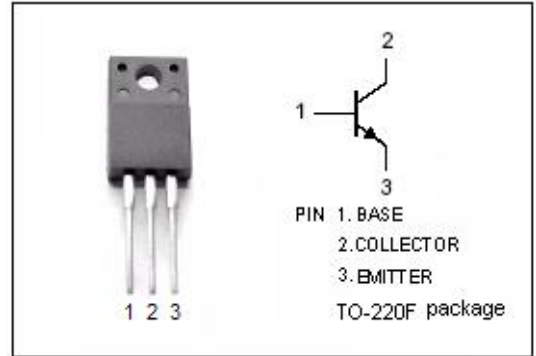


**isc Silicon NPN Power Transistor**
**2SC4130**
**DESCRIPTION**

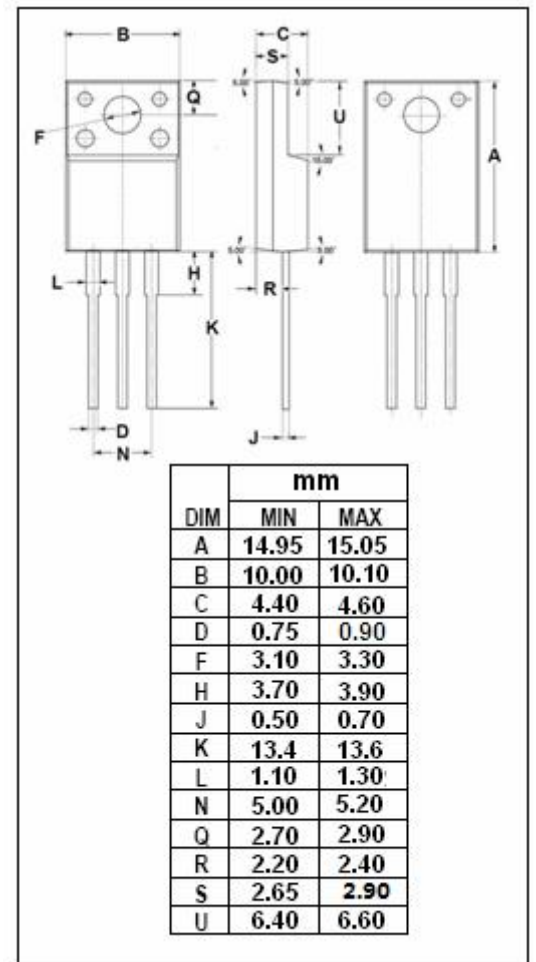
- Collector-Emitter Breakdown Voltage-  
:  $V_{(BR)CEO} = 400V(\text{Min})$
- High Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**APPLICATIONS**

- Designed for switching regulator and general purpose applications.


**ABSOLUTE MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	500	V
$V_{CEO}$	Collector-Emitter Voltage	400	V
$V_{EBO}$	Emitter-Base Voltage	10	V
$I_C$	Collector Current-Continuous	7	A
$I_{CM}$	Collector Current-Peak	14	A
$I_B$	Base Current-Continuous	2	A
$P_C$	Collector Power Dissipation @ $T_c = 25^\circ\text{C}$	30	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~150	$^\circ\text{C}$



**isc Silicon NPN Power Transistor**
**2SC4130**
**ELECTRICAL CHARACTERISTICS**

 T<sub>j</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 25mA; I <sub>B</sub> = 0	400			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.6A			0.5	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.6A			1.3	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 500V; I <sub>E</sub> = 0			100	μ A
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 10V; I <sub>C</sub> = 0			100	μ A
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 3A; V <sub>CE</sub> = 4V	10		30	
C <sub>OB</sub>	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f= 1MHz		50		pF
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>E</sub> = -0.5A; V <sub>CE</sub> = 12V		15		MHz

**Switching Times**

t <sub>on</sub>	Turn-On Time	I <sub>C</sub> = 3A; I <sub>B1</sub> = 0.3A; I <sub>B2</sub> = -0.6A; V <sub>CC</sub> = 200V; R <sub>L</sub> = 67 Ω			1.0	μ s
t <sub>stg</sub>	Storage Time				2.2	μ s
t <sub>f</sub>	Fall Time				0.5	μ s

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